

C2012X6S1V475M125AB

TDK Item Description : C2012X6S1V475MT****



Application & Main Feature

Commercial Grade (General (Up to 50V))

Series

C2012 [EIA CC0805]



Dimensions

L 2.00mm +/-0.2mm
 W 1.25mm +/-0.2mm
 T 1.25mm +/-0.2mm
 B 0.20mm Min.
 G 0.50mm Min.

Temperature Characteristic

X6S (-55 to 105 degC +/-22%)

Rated Voltage

1V (35Vdc)

Capacitance

4.7uF

Capacitance Tolerance

M (+/-20%)

Dissipation Factor

7.5% Max.

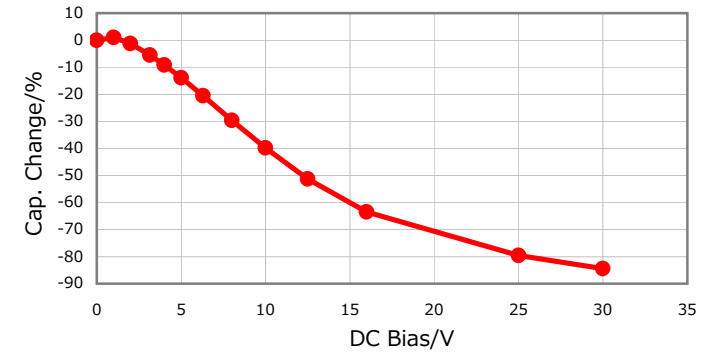
Insulation Resistance

106Mohm Min.

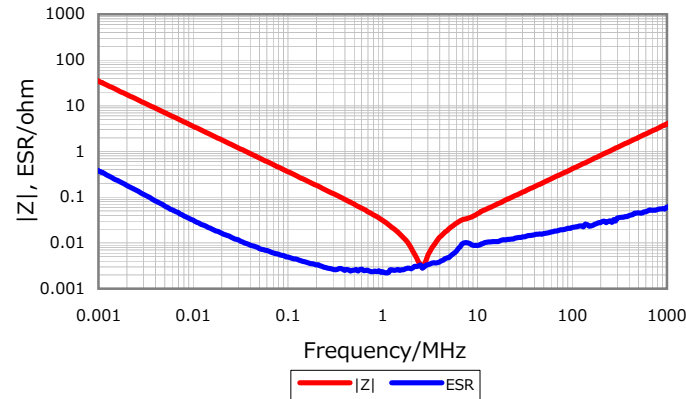
AEC-Q200

Not Applicable

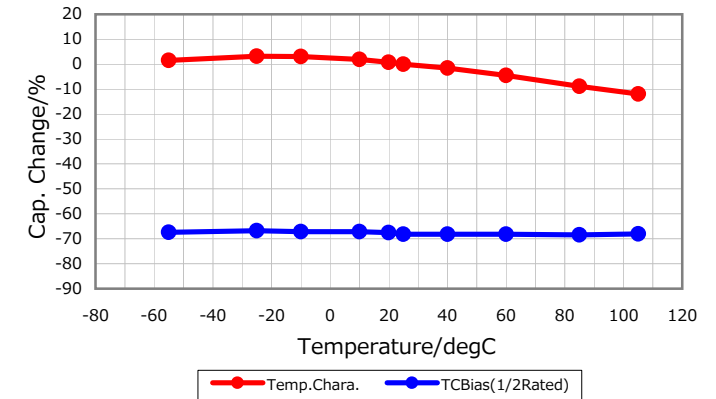
DC Bias Characteristic



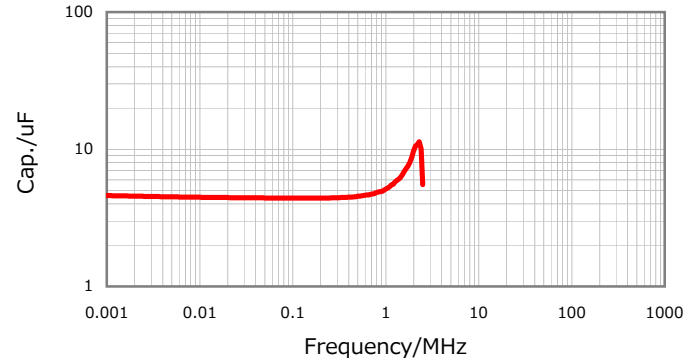
|Z|, ESR vs. Freq. Characteristics



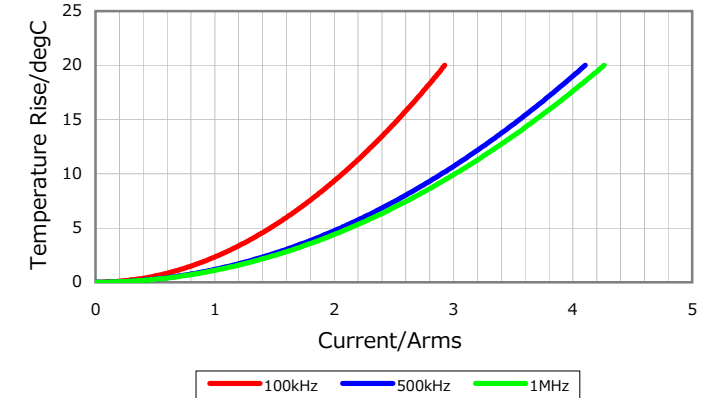
Temperature Characteristics



Cap. vs. Freq. Characteristic



Ripple Temperature Rise Characteristics



Characterization Sheet (Multilayer Ceramic Chip Capacitors)



All specifications are subject to change without notice.

January 3, 2016